NSN 5961-01-144-5527

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-144-5527 **Inclosure Material:** Metal **Overall Length:** 2.865 inches **Overall Height:** 0.670 inches **Overall Width:** 0.893 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 54.0 reverse voltage, dc and 66.3 regulator voltage **Current Rating Per Characteristic:** 5.00 milliamperes forward current, total rms nanoamperes and 171.00 amperes source cutoff current **Power Rating Per Characteristic:** 7.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 unthreaded hole Shelf Life: N/a **Unit Of Measure: Demilitarization:** No